

## JSD250

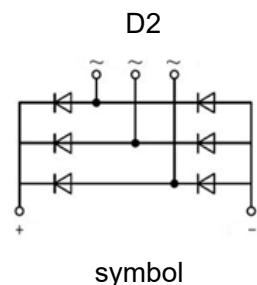
### Description

- 1) Low forward voltage and leakage current
- 2) Low inductance package
- 3) High surge current capability



### Typical Application

- 1) Field supply for DC motors
- 2) Line rectifiers for transistorized AC motor controllers
- 3) Non-controllable rectifiers for AC/DC converter



**Absolute Maximum Ratings** (Packaged into D2, unless otherwise specified,  $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values			Unit
			16	18	20	
Junction temperature range		$T_J$	$-40\text{~}+\text{150}$			°C
Storage temperature range		$T_{STG}$	$-40\text{~}+\text{125}$			°C
Repetitive peak reverse voltage		$V_{RRM}$	1600	1800	2000	V
Non-repetitive peak reverse voltage		$V_{RSM}$	1700	1900	2100	V
Output current	$T_c=95^{\circ}\text{C}$	$I_D$	250			A
Forward surge current	1/2 cycle, Sine wave 50Hz, $T_J=25^{\circ}\text{C}$	$I_{FSM}$	2800			A
Value for fusing		$I^2t$	39200			$\text{A}^2\text{s}$
RMS isolation voltage	A.C 50Hz(1s/1min)	$V_{ISO}$	3600/3000			V



## Three Phase Rectifier Bridge Module

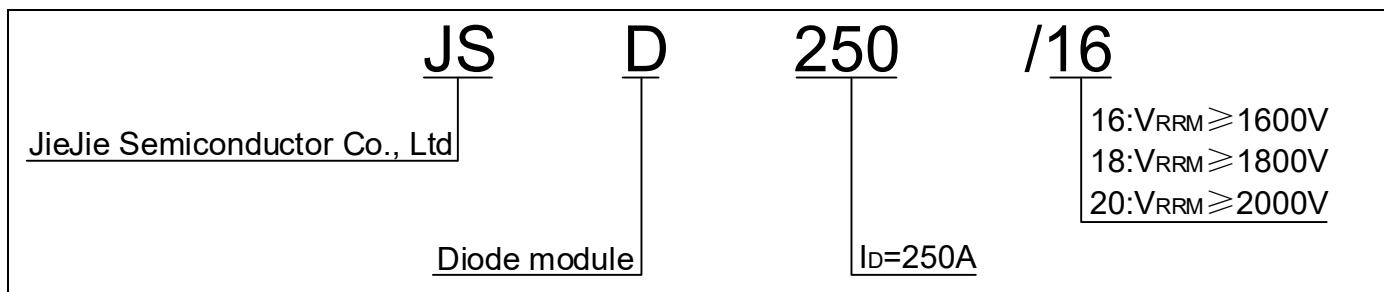
**Electrical Characteristics** (Packaged into D2, unless otherwise specified,  $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Forward voltage	$I_F=250\text{A}, T_J=25^{\circ}\text{C}$	$V_{FM}$	-	-	1.35	V
Reverse leakage current	$V_R=V_{RRM}, T_J=25^{\circ}\text{C}$	$I_{RRM}$	-	-	0.5	mA
	$V_R=V_{RRM}, T_J=150^{\circ}\text{C}$		-	-	10	mA
Threshold voltage	$T_J=150^{\circ}\text{C}$ , for power loss calculation only	$V_{TO}$	-	-	0.95	V
Slope resistance		$r_T$	-	-	1.5	mΩ

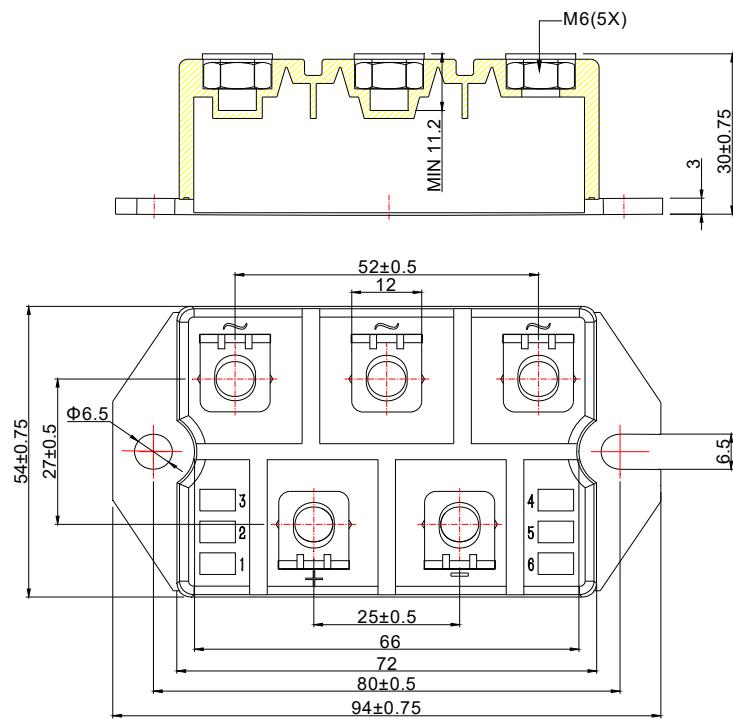
**Thermal Characteristics** (Packaged into D2, unless otherwise specified,  $T_{CASE}=25^{\circ}\text{C}$ )

Parameter	Test Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Thermal impedance (junction to case)	Per diode	$R_{th(j-c)}$	-	-	0.58	°C/W
Mounting torque	Module and heatsink fixed torque, screw M6	M	4.25	-	5.75	Nm
	Electrode connection torque, screw M6		4.25	-	5.75	Nm
Weight			240			g
Case style			D2			

### Ordering Information

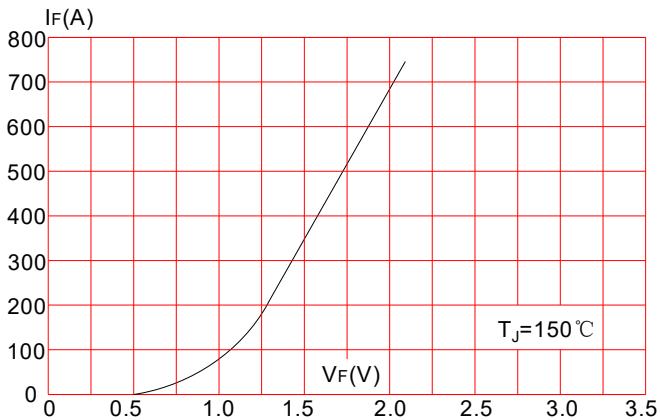


## Mechanical Characteristics(mm)

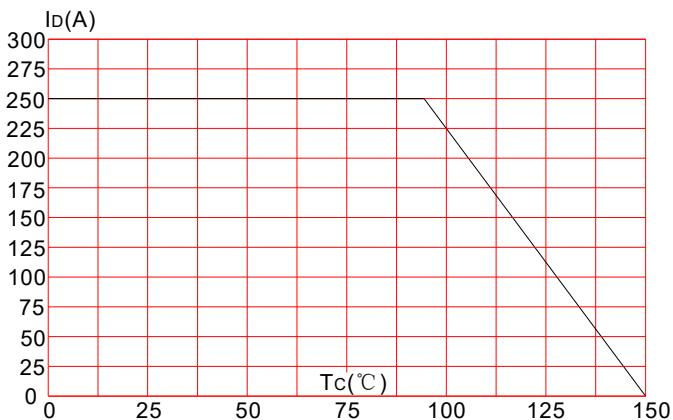


## Performance Curves

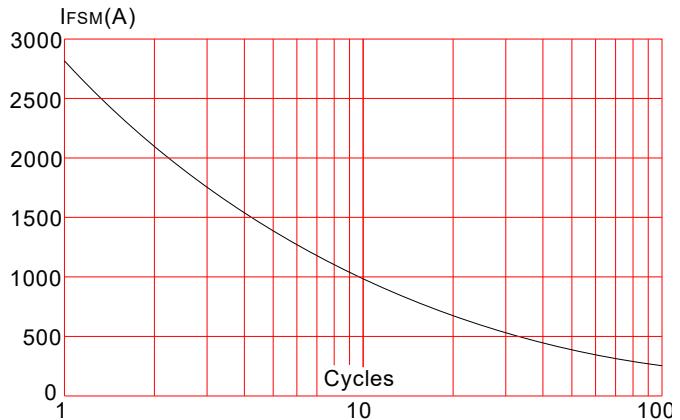
**FIG.1:** Forward characteristics(per diode)



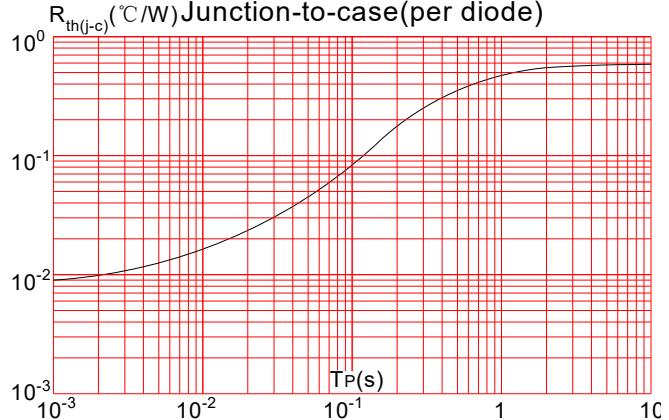
**FIG.3:** Forward current vs. case temperature



**FIG.2:** Peak on-state surge current



**FIG.4:** Maximum transient thermal impedance



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